

Title (en)
LIGHT-EMITTING DIODE AND METHOD FOR PRODUCING A LIGHT-EMITTING DIODE

Title (de)
LEUCHTDIODE UND VERFAHREN ZUR HERSTELLUNG EINER LEUCHTDIODE

Title (fr)
DIODE LUMINESCENTE ET PROCÉDÉ DE FABRICATION D'UNE DIODE LUMINESCENTE

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Application
EP 10725804 A 20100629

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Abstract (en)
[origin: WO2011006754A1] The invention relates to a light-emitting diode comprising: a carrier (1) having a mounting surface (1a); at least one light-emitting diode chip (2, 2a, 2b, 2c) attached to the mounting surface (1a); and a reflecting element (3) provided for reflecting electromagnetic radiation (4), wherein: the reflecting element (3) is attached to the carrier (1); and the reflecting element (3) comprises porous polytetrafluoroethylene.

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H01L 33/60 (2010.01)

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See references of WO 2011006754A1

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